



FAST RECOVERY RECTIFIER

ERB43-02---EB43-04

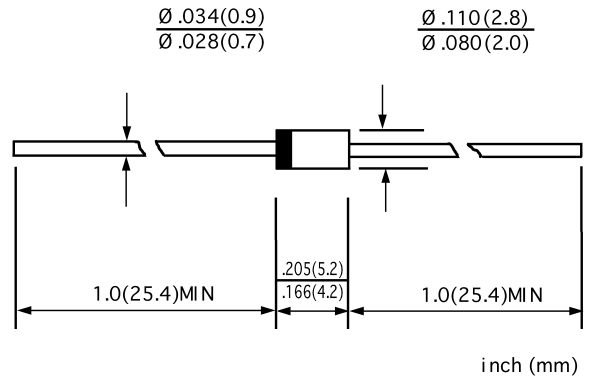
VOLTAGE RANGE: 200 --- 400 V

CURRENT: 0.5 A

FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Freon, Alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

DO - 41



MECHANICAL DATA

- ◇ Case: JEDEC DO-41, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.012 ounces, 0.34 grams
- ◇ Mounting position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		ERB43-02	ERB43-04	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	200	400	V
Maximum RMS voltage	V_{RMS}	140	280	V
Maximum DC blocking voltage	V_{DC}	200	400	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	0.5		A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	I_{FSM}	20.0		A
Maximum instantaneous forward voltage @ 0.5 A	V_F	1.2		V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	I_R	5.0	100.0	μA
Maximum reverse recovery time (Note1)	t_{rr}	400		ns
Typical junction capacitance (Note2)	C_J	12		pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	55		$^\circ\text{C/W}$
Operating junction temperature range	T_J	-55----+150		$^\circ\text{C}$
Storage temperature range	T_{STG}	-55----+150		$^\circ\text{C}$

NOTE:1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{rr}=0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

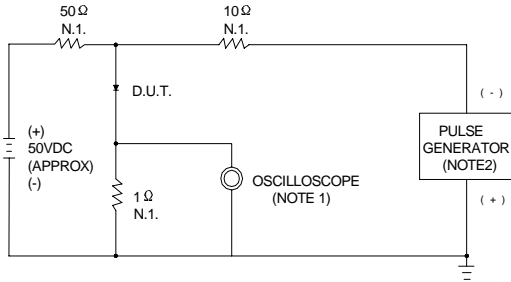
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FIG.1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = 1MΩ, 22pF
2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50Ω

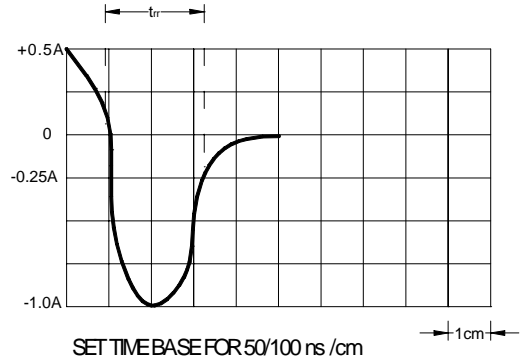


FIG.2 – TYPICAL FORWARD CHARACTERISTIC

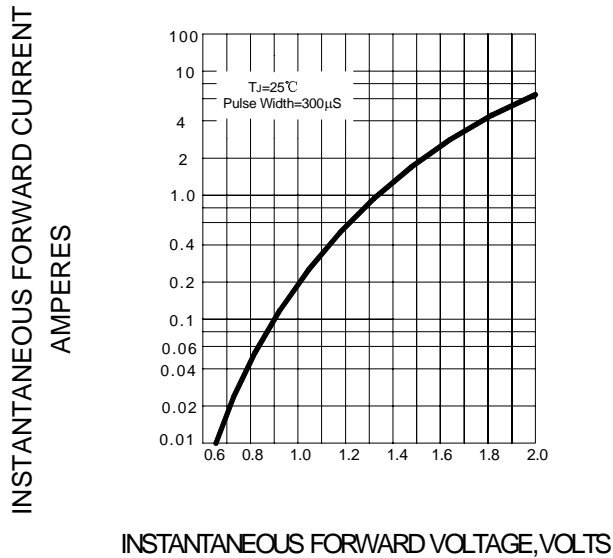


FIG.3 – FORWARD DERATING CURVE

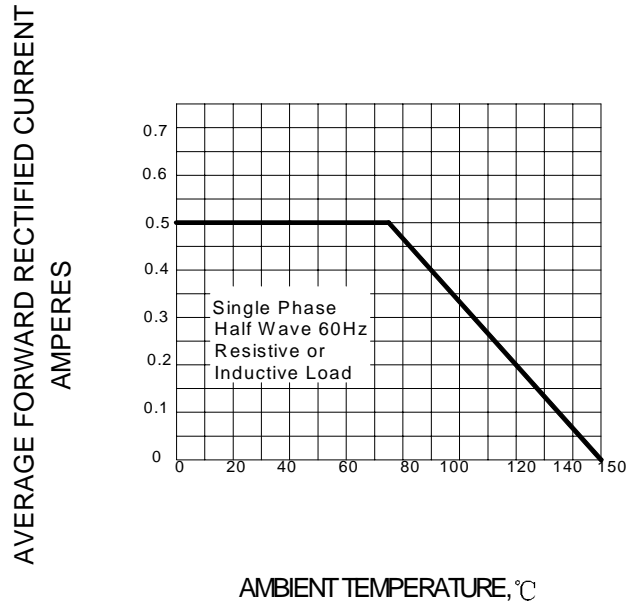


FIG.4 – TYPICAL JUNCTION CAPACITANCE

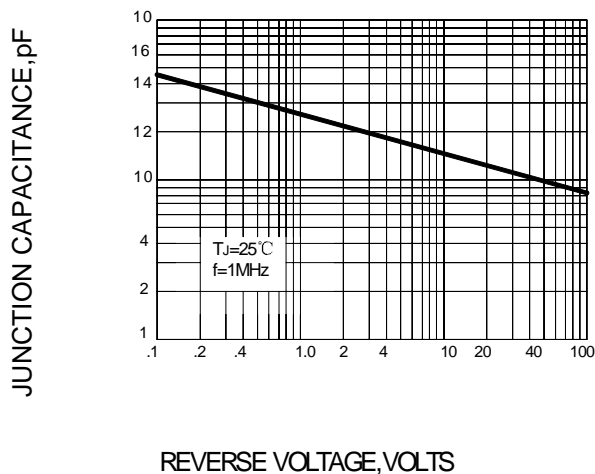


FIG.5 – PEAK FORWARD SURGE CURRENT

